

DM74ALS5245/74ALS5245-1 Octal 3-STATE Transceiver

General Description

This octal bus transceiver is designed for asynchronous two-way communication between data buses. The inputs include hysteresis which provides improved noise rejection. Data is transmitted either from the A bus to the B bus or from the B bus to the A bus depending on the logic level of the direction control (DIR) input. The device can be disabled via the enable input $\overline{(G)}$) which causes the outputs to enter the high impedance mode so the buses are effectively isolated.

The ALS5245-1 features the same performance as the ALS5245 with the addition of increased current drive capability to meet the requirements of various bus architectures. The recommended maximum $\rm I_{OL}$ is increased to 48 mA.

Features

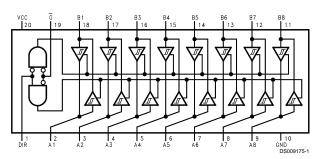
- Input Hysteresis
- Low output noise generation
- High input noise immunity
- Advanced oxide-isolated, ion implanted Schottky TTL process
- Switching specification guaranteed over the full temperature and V_{CC} range
- PNP inputs to reduce input loading
- Maximum I_{OI} is increased to 48 mA for ALS5245-1

Ordering Code:

| Order Number | Package Number | Package Description |
|-----------------|----------------|-------------------------------------------|
| DM74ALS5245WM | M20B | 20-Lead Small Outline Package – JEDEC (M) |
| DM74ALS5245SJ | M20D | 20-Lead Small Outline Package – EIAJ (SJ) |
| DM74ALS5245N | N20A | 20-Lead Molded Dual-in-Line Package (N) |
| DM74ALS5245-1WM | M20B | 20-Lead Small Outline Package – JEDEC (M) |
| DM74ALS5245-1SJ | M20D | 20-Lead Small Outline Package – EIAJ (SJ) |
| DM74ALS5245-1N | N20A | 20-Lead Molded Dual-in-Line Package (N) |

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Connection Diagram



Function Table

| Control Inputs G DIR | | Operation | | |
|----------------------|---|-----------------|--|--|
| | | | | |
| L | L | B Data to A Bus | | |
| L | Н | A Data to B Bus | | |
| Н | Х | High Impedance | | |

L = Low Logic Level, H = High Logic Level X = Don't Care (Either Low or High Logic Level) **Absolute Maximum Ratings** (Note 1)

Operating Free-Air Temperature Range

Supply Voltage 7V

DM74ALS Storage Temperature Range 0°C to +70°C -65°C to +150°C

Input Voltage
Control Inputs

Typical θ_{JA} N Package M Package

56.0°C/W 74.0°C/W

Recommended Operating Conditions

| Symbol | Parameter | DM74ALS5245 | | 74ALS | Units | |
|-----------------|--------------------------------------|-------------|-----|-------|-------|----|
| | | Min | Max | Min | Max | |
| V _{CC} | Supply Voltage | 4.5 | 5.5 | 4.5 | 5.5 | V |
| V _{IH} | High Level Input Voltage | 2 | | 2 | | V |
| V _{IL} | Low Level Input Voltage | | 0.8 | | 0.8 | V |
| I _{OH} | High Level Output Current | | -15 | | -15 | mA |
| I _{OL} | Low Level Output Current | | 24 | | 48 | mA |
| T _A | Free Air Operating Temperature Range | 0 | 70 | 0 | 70 | °C |

7V

5.5V

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristic tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

ALS5245

I/O Ports

Electrical Characteristics

over recommended free air temperature range. All typical values are measured at V_{CC} = 5V, T_A = 25°C.

| Symbol | Parameter | Test | Test Conditions | | DM74ALS5245 | | |
|------------------|-------------------------------------------------|------------------------------------------------|------------------------------------------------|---------------------|-------------|------|----|
| | | | | Min | Тур | Max | 1 |
| V _{IK} | Input Clamp Voltage | V _{CC} = Min, I _I = -18 mA | V _{CC} = Min, I _I = -18 mA | | | -1.5 | V |
| H _{YS} | Hysteresis (V _{T+} – V _{T-}) | V _{CC} = Min | | 0.2 | 0.32 | | V |
| V _{OH} | High Level Output | V _{CC} = 4.5V to 5.5V | I _{OH} = -0.4 mA | V _{CC} - 2 | | | |
| | Voltage | V _{CC} = Min | I _{OH} = -3 mA | 2.4 | 3.2 | | V |
| | | | I _{OH} = Max | 2 | | | 1 |
| V _{OL} | Low Level Output | V _{CC} = Min | I _{OL} = 12 mA | | 0.25 | 0.4 | V |
| | Voltage | | I _{OL} = 24 mA | | 0.35 | 0.5 | 1 |
| I _I | Input Current at | V _{CC} = Max | I/O Ports, V _I = 5.5V | | | 100 | μA |
| | Maximum Input Voltage | | Control Inputs, V _I = 7V | | | 100 | 1 |
| I _{IH} | High Level Input Current | V _{CC} = Max, V _I = 2.7V | | | | 20 | μA |
| I _{IL} | Low Level Input Current | V _{CC} = Max, V _I = 0.4V | | | | -100 | μA |
| Io | Output Drive Current | V _{CC} = Max, V _O = 2.25\ | 1 | -30 | | -112 | mA |
| Icc | Supply Current | V _{CC} = Max | Outputs High | | 30 | 45 | |
| | | | Outputs Low | | 36 | 55 | mA |
| | | | Outputs Disabled | | 38 | 58 | |
| V _{OLP} | Quiet Output Maximum | V _{CC} = 5.0V, T _A = 25°C | | | 0.5 | | V |
| | Dynamic V _{OL} | (Figures 1, 2; (Notes 2 | , 3)) | | | | |
| V _{OLV} | Quiet Output Minimum | V _{CC} = 5.0V, T _A = 25°C | | | -0.2 | | V |
| | Dynamic V _{OL} | (Figures 1, 2; (Notes 2 | , 3)) | | | | |
| V _{IHD} | Minimum High Level | V _{CC} = 5.0V, T _A = 25°C | | | 1.6 | | V |
| | Dynamic Input Voltage | (Notes 2, 4) | | | | | |
| V _{ILD} | Maximum Low Level | V _{CC} = 5.0V, T _A = 25°C | | | 1.0 | | V |
| | Dynamic Input Voltage | (Notes 2, 4) | | | | | |
| | | | | | | | |

Note 2: Plastic DIP package.

Note 3: n = number of device outputs; n-1 outputs switching, each driven 0V to 3V one output @ GND.

Note 4: n = number of device outputs; n outputs switching, n-1 inputs switching 0V to 3V. Input under test switching 3V to threshold (V_{ILD}); 0V to threshold (V_{IHD}); f = 1 MHz.

Switching Characteristicsover recommended operating free air temperature range (Note 5)

| Symbol | Parameter | Conditions | From (Input) | DM74ALS5245 | | Units |
|------------------|--------------------------|---------------------------------|--------------|-------------|-----|-------|
| | | | To (Output) | Min | Max | 1 |
| t _{PLH} | Propagation Delay Time | V _{CC} = 4.5V to 5.5V, | A or B to | 3 | 10 | ns |
| | Low to High Level Output | $R_1 = R_2 = 500\Omega,$ | B or A | | | |
| t _{PHL} | Propagation Delay Time | C _L = 50 pF | A or B to | 3 | 10 | ns |
| | High to Low Level Output | | B or A | | | |
| t _{PZH} | Output Enable Time | | G to | 5 | 20 | ns |
| | to High Level Output | | A or B | | | |
| t _{PZL} | Output Enable Time | | G to | 5 | 20 | ns |
| | to Low Level Output | | A or B | | | |
| t _{PHZ} | Output Disable Time | | G to | 2 | 10 | ns |
| | from High Level Output | | A or B | | | |
| t _{PLZ} | Output DisableTime | | G to | 4 | 15 | ns |
| | from Low Level Output | | A or B | | | |

Note 5: See Section 5 for test waveforms and output load.

ALS5245-1

Electrical Characteristics

over recommended free air temperature range

| Symbol | Parameter | Te | Test Conditions | | 74ALS5245-1 | | |
|------------------|-------------------------------------------------|------------------------------------------------|-------------------------------------------------------|---------------------|-------------|------|----|
| | | | | Min | Тур | Max | 1 |
| V _{IC} | Input Clamp Voltage | V _{CC} = Min, I _I = -18 mA | V _{CC} = Min, I _I = -18 mA | | | -1.5 | V |
| H _{YS} | Hysteresis (V _{T+} - V _{T-}) | V _{CC} = Min | | 0.2 | 0.32 | | V |
| V _{OH} | High Level Output | V _{CC} = 4.5V to 5.5V | I _{OH} = -0.4 mA | V _{CC} - 2 | | | |
| | Voltage | V _{CC} = Min | I _{OH} = -3 mA | 2.4 | 3.2 | | V |
| | | | I _{OH} = Max | 2 | | | 1 |
| V _{OL} | Low Level Output | V _{CC} = Min | I _{OL} = 48 mA | | 0.45 | 0.53 | V |
| | Voltage | | | | | | |
| - I _I | Input Current at | V _{CC} = Max | I/O Ports, V _I = 5.5V | | | 100 | μΑ |
| | Maximum Input Voltage | | Control Inputs, V _I = 7V | | | 100 | 1 |
| I _{IH} | High Level Input Current | V _{CC} = Max, V _I = 2.7V (| V _{CC} = Max, V _I = 2.7V (Note 6) | | | 20 | μΑ |
| I _{IL} | Low Level Input Current | V _{CC} = Max, V _I = 0.4V (| (Note 6) | | | -100 | μΑ |
| Io | Output Drive Current | V _{CC} = Max, V _O = 2.25 | / | -30 | | -112 | mA |
| Icc | Supply Current | V _{CC} = Max | Outputs High | | 30 | 45 | |
| | | | Outputs Low | | 36 | 55 | mA |
| | | | Outputs Disabled | | 38 | 58 | 1 |

 $\textbf{Note 6:} \ \ \text{For I/O ports, I}_{\text{IH}} \ \text{and I}_{\text{IL}} \ \text{parameters include the 3-STATE output currents (I}_{\text{OZL}} \ \text{and I}_{\text{OZH}}).$

Switching Characteristicsover recommended operating free air temperature range (Note 7)

| Symbol | Parameter | Conditions | From (Input) | 74ALS5245-1 | | Units |
|------------------|--------------------------|---------------------------------|--------------|-------------|-----|-------|
| | | | To (Output) | Min | Max | 1 |
| t _{PLH} | Propagation Delay Time | V _{CC} = 4.5V to 5.5V, | A or B to | 2 | 10 | ns |
| | Low to High Level Output | $R_1 = R_2 = 500\Omega,$ | B or A | | | |
| t _{PHL} | Propagation Delay Time | C _L = 50 pF | A or B to | 3 | 10 | ns |
| | High to Low Level Output | | B or A | | | |
| t _{PZH} | Output Enable Time | | G to | 4 | 20 | ns |
| | to High Level Output | | A or B | | | |
| t _{PZL} | Output Enable Time | | G to | 5 | 20 | ns |
| | to Low Level Output | | A or B | | | |
| t _{PHZ} | Output Disable Time | | G to | 1 | 10 | ns |
| | from High Level Output | | A or B | | | |
| t _{PLZ} | Output DisableTime | | G to | 3 | 15 | ns |
| | from Low Level Output | | A or B | | | |

Note 7: See Section 5 for test waveforms and output load.

ALS Noise Characteristics

The setup of a noise characteristics measurement is critical to the accuracy and repeatability of the tests. The following is a brief description of the setup used to measure the noise characteristics of ALS.

Equipment:

Word Generator

Printed Circuit Board Test Fixture

Dual Trace Oscilloscope

Procedure:

- 1. Verify Test Fixture Loading: Standard Load 50 pF, 500Ω .
- 2. Deskew the word generator so that no two channels have greater than 150 ps skew between them. This requires that the oscilloscope be deskewed first. Swap out the channels that have more than 150 ps of skew until all channels being used are within 150 ps. It is important to deskew the word generator channels before testing. This will ensure that the outputs switch simultaneously.
- Terminate all inputs and outputs to ensure proper loading of the outputs and that the input levels are at the correct voltage.
- 4. Set $V_{\rm CC}$ to 5.0V.
- Set the word generator to toggle all but one output at a frequency of 1 MHz. Greater frequencies will increase DUT heating and affect the results of the measurement.
- Set the word generator input levels at 0V LOW and 3V HIGH. Verify levels with a digital volt meter.

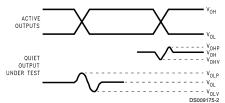


FIGURE 1. Quiet Output Noise Voltage Waveforms

Note 8: V_{OHV} and V_{OHP} are measured with respect to V_{OH} reference. V_{OLV} and V_{OLP} are measured with respect to ground reference.

Note 9: Input pulses have the following characteristics: f = 1 MHz, $t_{\rm f}$ = 3 ns, skew < 150 ps.

$\rm V_{\rm OLP}/\rm V_{\rm OLV}$ and $\rm V_{\rm OHP}/\rm V_{\rm OHV}$:

- Determine the quiet output pin that demonstrates the greatest noise levels. The worst case pin will usually be the furthest from the ground pin. Monitor the output voltages using a 50\Omega coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- Measure V_{OLP} and V_{OLV} on the quiet output during the HL transition. Measure V_{OHP} and V_{OHV} on the quiet output during the LH transition.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

V_{ILD} and V_{IHD} :

- Monitor one of the switching outputs using a 50Ω coaxial cable plugged into a standard SMB type connector on the test fixture. Do not use an active FET probe.
- First increase the input LOW voltage level, V_{IL}, until the output begins to oscillate. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input LOW voltage level at which oscillation occurs is defined as V_{ILD}.
- Next decrease the input HIGH voltage level on the word generator, V_{IH} until the output begins to oscillate. Oscillation is defined as noise on the output LOW level that exceeds V_{IL} limits, or on output HIGH levels that exceed V_{IH} limits. The input HIGH voltage level at which oscillation occurs is defined as V_{IHD}.
- Verify that the GND reference recorded on the oscilloscope has not drifted to ensure the accuracy and repeatability of the measurements.

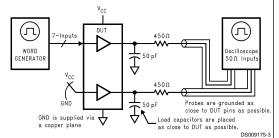
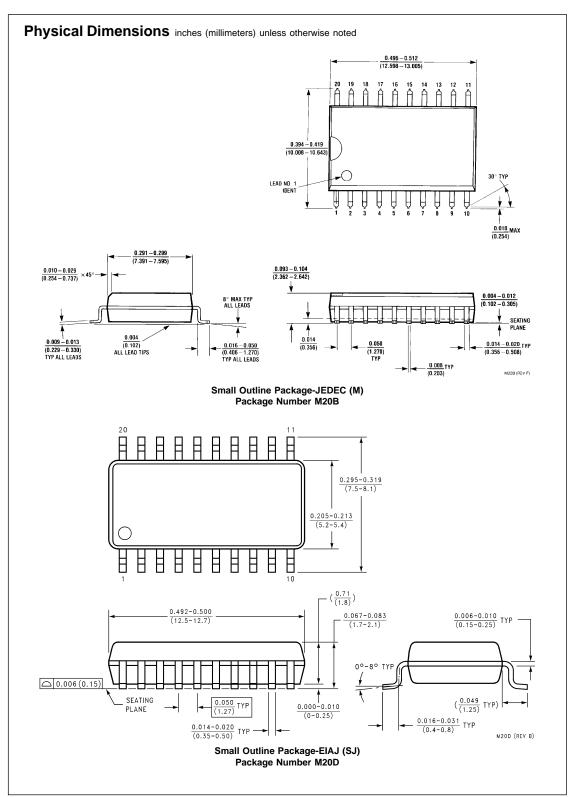
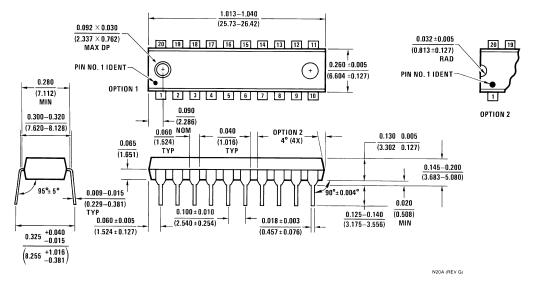


FIGURE 2. Simultaneous Switching Test Circuit



Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Molded Dual-In-Line Package (N) Package Number N20A

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